### 8.89mm x 3.81mm LED LIGHT BAR

Part Number: KB-2600SEKW

Super Bright Orange

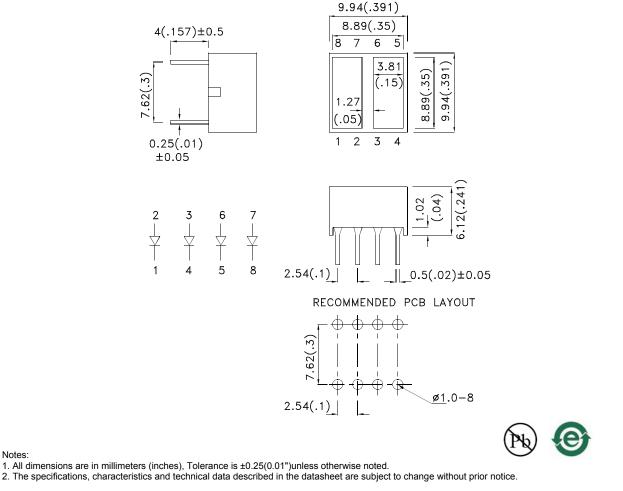
### **Features**

- Uniform light emitting area.
- Low current operation
- Easily mounted on P.C.boards.
- Flush mountable.
- Excellent on/off contrast.
- Can be used with panels and legend mounts.
- Categorized for luminous intensity.
- RoHS compliant.

#### Description

The Super Bright Orange device is made with AlGaInP (on GaAs substrate) light emitting diode chip.

### Package Dimensions& Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters (inches), Tolerance is ±0.25(0.01")unless otherwise noted.

DATE: MAY/20/2010 **DRAWN: C.H.Han** 

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Selection Guide								
Part No.	Dice	Lens Type	lv (mcd) [1] @ 20mA					
			Min.	Тур.				
KB-2600SEKW	Super Bright Orange (AlGaInP)	WHITE DIFFUSED	280	465				

Note:

1. Luminous intensity/ luminous Flux: +/-15%.

### Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Orange	610		nm	I⊧=20mA
λD [1]	Dominant Wavelength	Super Bright Orange	601		nm	I⊧=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Orange	29		nm	I⊧=20mA
С	Capacitance	Super Bright Orange	15		pF	VF=0V;f=1MHz
Vf [2]	Forward Voltage	Super Bright Orange	2.1	2.5	V	I⊧=20mA
lr	Reverse Current	Super Bright Orange		10	uA	VR=5V

Notes:

1.Wavelength: +/-1nm.

2. Forward Voltage: +/-0.1V.

### Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Orange	Units		
Power dissipation	75	mW		
DC Forward Current	30	mA		
Peak Forward Current [1]	195	mA		
Reverse Voltage	5	V		
Operating / Storage Temperature	g / Storage Temperature -40°C To +85°C			
Lead Solder Temperature[2]	ad Solder Temperature[2] 260°C For 3-5 Seconds			

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 2mm below package base.

